

MOC3060, MOC3061, MOC3062, MOC3063
MOC3060X, MOC3061X, MOC3062X, MOC3063X



ISOCOM
COMPONENTS



OPTICALLY COUPLED BILATERAL SWITCH LIGHT ACTIVATED ZERO VOLTAGE CROSSING TRIAC

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form : -
- STD
- G form
- SMD approved to CECC 00802
- -UL recognised File No. E91231
Package system " TT "

DESCRIPTION

The MOC306_ Series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode coupled with a monolithic silicon detector performing the functions of a zero crossing bilateral triac mounted in a standard 6 pin dual-in-line package.

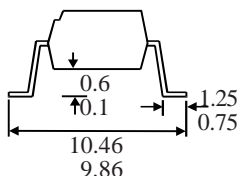
FEATURES

- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High Isolation Voltage, 5.3kV_{RMS}
- Zero Voltage Crossing
- 600V Peak Blocking Voltage
- All electrical parameters 100% tested
- Custom electrical selections available

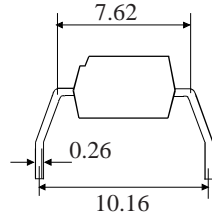
APPLICATIONS

- CRTs
- Power Triac Driver
- Motors
- Consumer appliances

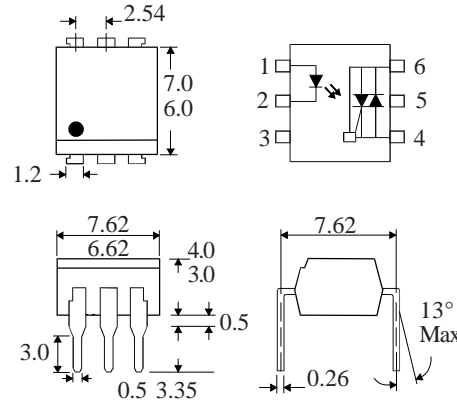
OPTION SM SURFACE MOUNT



OPTION G



Dimensions in mm



ABSOLUTE MAXIMUM RATINGS (25 °C unless otherwise noted)

Storage Temperature _____ -55°C-+150°C
Operating Temperature _____ -40°C-+100°C
Lead Soldering Temperature _____ 260°C
(1.6mm from case for 10 seconds)

INPUT DIODE

Forward Current _____ 50mA
Reverse Voltage _____ 6V
Power Dissipation _____ 120mW
(derate linearly 1.41mW/°C above 25°C)

OUTPUT PHOTO TRIAC

Off-State Output Terminal Voltage _____ 600V
Forward Current (Peak) _____ 1A
Power Dissipation _____ 150mW
(derate linearly 1.76mW/°C above 25°C)

POWER DISSIPATION

Total Power Dissipation _____ 250mW
(derate linearly 2.94mW/°C above 25°C)

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F) Reverse Current (I_R)		1.2 0.05	1.4 10	V μA	$I_F = 20\text{mA}$ $V_R = 6\text{V}$
Output	Peak Off-state Current (I_{DRM}) Peak Blocking Voltage (V_{DRM}) On-state Voltage (V_{TM}) Critical rate of rise of off-state Voltage (dv/dt)	600		500 3.0	nA V V $\text{V}/\mu\text{s}$	$V_{\text{DRM}} = 600\text{V}$ (note 1) $I_{\text{DRM}} = 500\text{nA}$ $I_{\text{TM}} = 100\text{mA}$ (peak)
Coupled	Input Current to Trigger (I_{FT})(note 2) MOC3060 MOC3061 MOC3062 MOC3063 Holding Current , either direction (I_H) Input to Output Isolation Voltage V_{ISO}			30 15 10 5	mA mA mA mA μA V_{RMS}	$V_{\text{TM}} = 3\text{V}$ (note 2) See note 3
Zero Crossing Charact- -eristic	Inhibit Voltage (V_{IH}) Leakage in Inhibited State (I_S)			20 500	V μA	$I_F = \text{Rated } I_{\text{FT}}$ MT1-MT2 Voltage above which device will not trigger $I_F = \text{Rated } I_{\text{FT}}$ $V_{\text{DRM}} = 600\text{V}$ off-state

Note 1. Test voltage must be applied within dv/dt rating.

Note 2. Guaranteed to trigger at an I_F value less than or equal to max. I_{FT} , recommended I_F lies between Rated I_{FT} and absolute max. I_F .

Note 3. Measured with input leads shorted together and output leads shorted together.